MC74VHC541

Octal Bus Buffer

The MC74VHC541 is an advanced high speed CMOS octal bus buffer fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining CMOS low power dissipation.

The MC74VHC541 is a noninverting type. When either $\overline{OE1}$ or $\overline{OE2}$ are high, the terminal outputs are in the high impedance state.

The internal circuit is composed of three stages, including a buffer output which provides high noise immunity and stable output. The inputs tolerate voltages up to 7.0 V, allowing the interface of 5.0 V systems to 3.0 V systems.

Features

- High Speed: $t_{PD} = 3.7$ ns (Typ) at $V_{CC} = 5.0$ V
- Low Power Dissipation: $I_{CC} = 4 \mu A$ (Max) at $T_A = 25^{\circ}C$
- High Noise Immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$
- Power Down Protection Provided on Inputs
- Balanced Propagation Delays
- Designed for 2.0 V to 5.5 V Operating Range
- Low Noise: $V_{OLP} = 1.2 V$ (Max)
- Pin and Function Compatible with Other Standard Logic Families
- Latchup Performance Exceeds 300mA
- ESD Performance: HBM > 2000 V; Machine Model > 200 V
- Chip Complexity: 134 FETs or 33.5 Equivalent Gates
- These Devices are Pb-Free and are RoHS Compliant

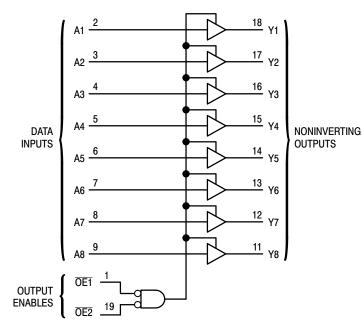
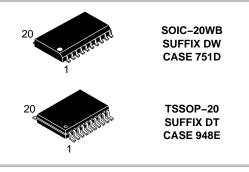


Figure 1. Logic Diagram



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PIN ASSIGNMENT

| OE1 | 1● | 20 | □ v _{cc} |
|-------|----|----|-------------------|
| A1 [| 2 | 19 | |
| A2 [| 3 | 18 | D Y1 |
| A3 [| 4 | 17 |] Y2 |
| A4 [| 5 | 16 |] Y3 |
| A5 [| 6 | 15 |] Y4 |
| A6 [| 7 | 14 |] Y5 |
| A7 [| 8 | 13 |] Y6 |
| A8 [| 9 | 12 |] Y7 |
| GND [| 10 | 11 |] Y8 |

| FUNCTION TABLE | | | | | |
|----------------|--------|--------|----------|--|--|
| | Inputs | | Output Y | | |
| OE1 | OE2 | Α | Output I | | |
| L | L | L | L | | |
| L H | X | H X | H Z | | |
| Х | Н | Х | Z | | |

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 4 of this data sheet.

MAXIMUM RATINGS

| Symbol | Parameter | Parameter | | Unit |
|------------------|-----------------------------------|---------------------------------|----------------|------|
| V _{CC} | DC Supply Voltage | | – 0.5 to + 7.0 | V |
| V _{in} | DC Input Voltage | – 0.5 to + 7.0 | V | |
| V _{out} | DC Output Voltage | -0.5 to V _{CC} + 0.5 | V | |
| I _{IK} | Input Diode Current | - 20 | mA | |
| I _{OK} | Output Diode Current | ± 20 | mA | |
| I _{out} | DC Output Current, per Pin | | ± 25 | mA |
| I _{CC} | DC Supply Current, V_{CC} and G | ND Pins | ± 50 | mA |
| PD | Power Dissipation in Still Air, | SOIC Package† TSSOP Package† | 500 450 | mW |
| T _{stg} | Storage Temperature | | – 65 to + 150 | °C |

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range GND $\leq (V_{in} \text{ or } V_{out}) \leq V_{CC}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

†Derating — SOIC Package: – 7 mW/°C from 65° to 125°C

TSSOP Package: – 6.1 mW/°C from 65° to 125°C

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Max | Unit |
|---------------------------------|--|--------|-----------------|------|
| V _{CC} | DC Supply Voltage | | 5.5 | V |
| Vin | DC Input Voltage | 0 | 5.5 | V |
| V _{out} | DC Output Voltage | 0 | V _{CC} | V |
| T _A | Operating Temperature, All Package Types | -55 | +125 | °C |
| t _r , t _f | Input Rise and Fall Time $$V_{CC}$=3.3V\pm\!0.3V$$ $$V_{CC}$=5.0V\pm\!0.5V$$ | 0 0 | 100 20 | ns/V |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

| | | | V | Т | _ _A = 25° | С | T _A = - 55 | to 125°C | j°C |
|-----------------|--------------------------------------|--|----------------------|-------------------------------|----------------------|-------------------------------|-------------------------------|-------------------------------|------|
| Symbol | Parameter | Test Conditions | V _{CC} V | Min | Тур | Max | Min | Max | Unit |
| V _{IH} | Minimum High-Level Input Voltage | | 2.0 3.0 to 5.5 | 1.50 V _{CC} x 0.7 | | | 1.50 V _{CC} x 0.7 | | V |
| V _{IL} | Maximum Low–Level Input Voltage | | 2.0 3.0 to 5.5 | | | 0.50 V _{CC} x 0.3 | | 0.50 V _{CC} x 0.3 | V |
| V _{OH} | Minimum High-Level Output Voltage | $V_{in} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -50 \mu A$ | 2.0 3.0 4.5 | 1.9 2.9 4.4 | 2.0 3.0 4.5 | | 1.9 2.9 4.4 | | V |
| | | $\label{eq:Vin} \begin{array}{l} V_{in} = V_{IH} \text{ or } V_{IL} \\ I_{OH} = - 4mA \\ I_{OH} = - 8mA \end{array}$ | 3.0 4.5 | 2.58 3.94 | | | 2.48 3.80 | | |
| V _{OL} | Maximum Low–Level Output Voltage | $V_{in} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 50 \mu A$ | 2.0 3.0 4.5 | | 0.0 0.0 0.0 | 0.1 0.1 0.1 | | 0.1 0.1 0.1 | V |
| | | $V_{in} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 4mA$ $I_{OL} = 8mA$ | 3.0 4.5 | | | 0.36 0.36 | | 0.44 0.44 | |
| l _{in} | Maximum Input Leakage Current | V _{in} = 5.5V or GND | 0 to 5.5 | | | ± 0.1 | | ±1.0 | μΑ |
| I _{OZ} | Maximum 3–State Leakage Current | $V_{in} = V_{IL} \text{ or } V_{IH}$ $V_{out} = V_{CC} \text{ or } GND$ | 5.5 | | | ± 0.25 | | ±2.5 | μΑ |
| Icc | Maximum Quiescent Supply Current | $V_{in} = V_{CC}$ or GND | 5.5 | | | 4.0 | | 40.0 | μΑ |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

MC74VHC541

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0$ ns)

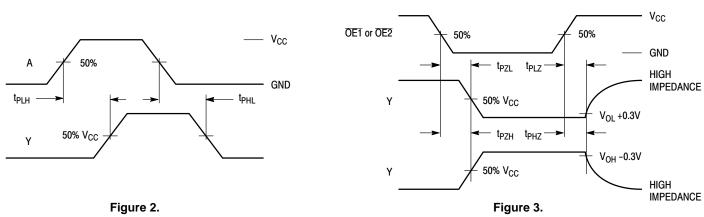
| | | | | T _A = 25°C | | T _A = − 55 to 125°C | | | |
|--|---|--|--|-----------------------|------------|--------------------------------|------------|--------------|------|
| Symbol | Parameter | Test Conditions | | Min | Тур | Мах | Min | Max | Unit |
| t _{PLH} , t _{PHL} | Maximum Propagation Delay, A to Y | $V_{CC} = 3.3 \pm 0.3 V$ | $C_L = 15pF$ $C_L = 50pF$ | | 5.0 7.5 | 7.0 10.5 | 1.0 1.0 | 8.5 12.0 | ns |
| | | $V_{CC} = 5.0 \pm 0.5 V$ | C _L = 15pF C _L = 50pF | | 3.5 5.0 | 5.0 7.0 | 1.0 1.0 | 6.0 8.0 | |
| t _{PZL} , t _{PZH} | Output Enable Time, OE to Y | $V_{CC} = 3.3 \pm 0.3 V$ $R_{L} = 1 k \Omega$ | C _L = 15pF C _L = 50pF | | 6.8 9.3 | 10.5 14.0 | 1.0 1.0 | 12.5 16.0 | ns |
| | | $V_{CC} = 5.0 \pm 0.5 V$ R _L = 1kΩ | C _L = 15pF C _L = 50pF | | 4.7 6.2 | 7.2 9.2 | 1.0 1.0 | 8.5 10.5 | |
| t _{PLZ} , t _{PHZ} | Output Disable Time, OE to Y | $V_{CC} = 3.3 \pm 0.3 V$ $R_{L} = 1 k \Omega$ | $C_L = 50 pF$ | | 11.2 | 15.4 | 1.0 | 17.5 | ns |
| | | $V_{CC} = 5.0 \pm 0.5 V$ R _L = 1kΩ | $C_L = 50 pF$ | | 6.0 | 8.8 | 1.0 | 10.0 | |
| t _{OSLH} , t _{OSHL} | Output to Output Skew | $\begin{array}{c} V_{CC} = 3.3 \pm 0.3 V \\ (\text{Note 1}) \end{array}$ | $C_L = 50 pF$ | | | 1.5 | | 1.5 | ns |
| | | $V_{CC} = 5.0 \pm 0.5 V$ (Note 1) | C _L = 50pF | | | 1.0 | | 1.0 | ns |
| C _{in} | Maximum Input Capacitance | | | | 4 | 10 | | 10 | pF |
| C _{out} | Maximum Three–State Output Capacitance (Output in High Impedance State) | | | | 6 | | | | pF |

| | | Typical @ 25°C, V _{CC} = 5.0V | | |
|-----------------|--|--|----|--|
| C _{PD} | Power Dissipation Capacitance (Note 2) | 18 | pF | |

Parameter guaranteed by design. t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|.
 C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC} / 8 (per bit). C_{PD} is used to determine the no-load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

NOISE CHARACTERISTICS (Input $t_r = t_f = 3.0$ ns, $C_L = 50$ pF, $V_{CC} = 5.0$ V)

| | | T _A = 25°C | | |
|------------------|--|-----------------------|-------|------|
| Symbol | Parameter | | Max | Unit |
| V _{OLP} | Quiet Output Maximum Dynamic V _{OL} | 0.9 | 1.2 | V |
| V _{OLV} | Quiet Output Minimum Dynamic V _{OL} | | - 1.2 | V |
| V _{IHD} | Minimum High Level Dynamic Input Voltage | | 3.5 | V |
| V _{ILD} | Maximum Low Level Dynamic Input Voltage | | 1.5 | V |



SWITCHING WAVEFORMS

MC74VHC541

TEST CIRCUITS

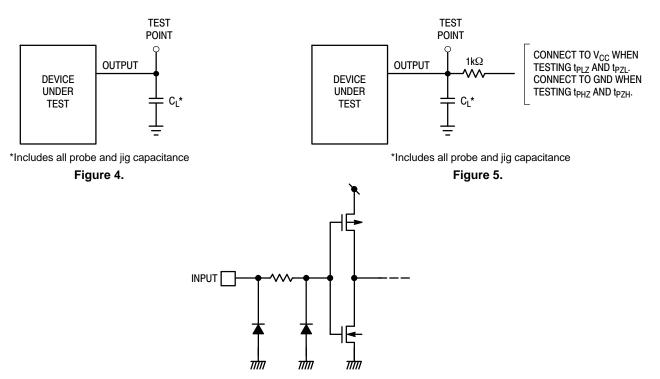


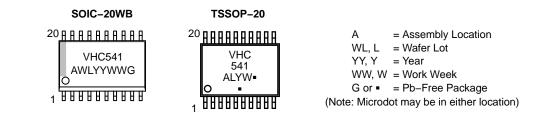
Figure 6. Input Equivalent Circuit

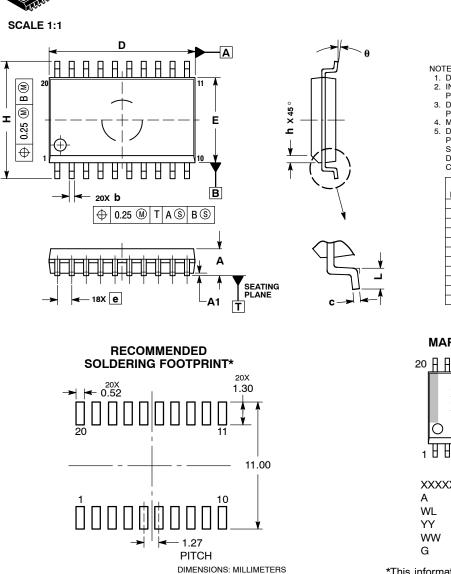
ORDERING INFORMATION

| Device | Package | Shipping [†] |
|-----------------|------------------------|-----------------------|
| MC74VHC541DWR2G | SOIC-20WB (Pb-Free) | 1000 / Tape & Reel |
| MC74VHC541DTG | TSSOP-20 (Pb-Free) | 75 Units / Rail |
| MC74VHC541DTR2G | TSSOP-20 (Pb-Free) | 2500 / Tape & Reel |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MARKING DIAGRAMS





*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DATE 22 APR 2015

DUSEM

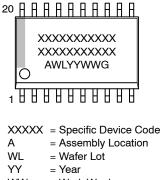
NOTES:

SOIC-20 WB CASE 751D-05 ISSUE H

- 1. DIMENSIONS ARE IN MILLIMETERS. 2. INTERPRET DIMENSIONS AND TOLERANCES
- PER ASME Y14.5M, 1994. 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
- DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

| | MILLIMETERS | | | |
|-----|-------------|-------|--|--|
| DIM | MIN | MAX | | |
| Α | 2.35 | 2.65 | | |
| A1 | 0.10 0.25 | | | |
| b | 0.35 0.49 | | | |
| C | 0.23 | 0.32 | | |
| D | 12.65 | 12.95 | | |
| Е | 7.40 | 7.60 | | |
| е | 1.27 | BSC | | |
| Н | 10.05 | 10.55 | | |
| h | 0.25 | 0.75 | | |
| L | 0.50 | 0.90 | | |
| θ | 0 ° | 7 ° | | |

GENERIC **MARKING DIAGRAM***

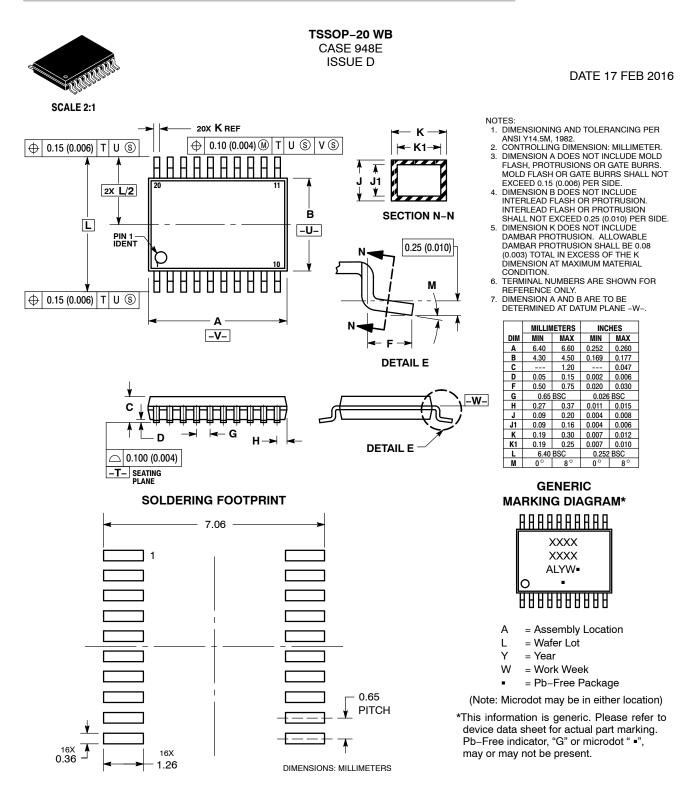


= Work Week = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb–Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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